

SMCJ-HR Series



Description

The SMCJ-HR High Reliability series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Agency Approvals

AGENCY	AGENCY FILE NUMBER
	E230531

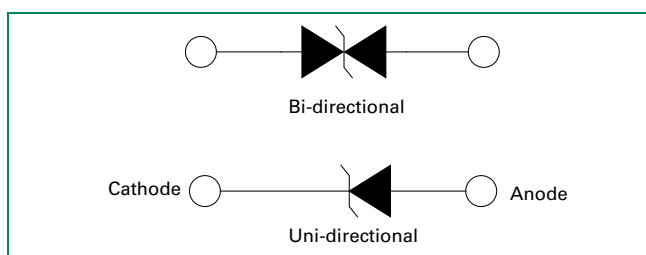
Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T _A =25°C by 10/1000µs waveform (Fig.1)(Note 1), (Note 2)	P _{PPM}	1500	W
Power Dissipation on infinite heat sink at T _A =50°C	P _{MAV}	6.5	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I _{FSM}	200	A
Maximum Instantaneous Forward Voltage at 100A for Unidirectional only (Note 4)	V _F	3.5/5.0	V
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-65 to 150	°C
Typical Thermal Resistance Junction to Lead	R _{θJL}	15	°C/W
Typical Thermal Resistance Junction to Ambient	R _{θJA}	75	°C/W

Notes:

1. Non-repetitive current pulse, per Fig. 3 and derated above T_A = 25°C per Fig. 2.
2. Mounted on copper pad area of 0.31x0.31" (8.0 x 8.0mm) to each terminal.
3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum.

Functional Diagram



Features

- For surface mounted applications in order to optimize board space
- Low profile package
- Built-in strain relief
- V_{BR} @T_J = V_{BR} @25°C x (1 + α T x (T_J - 25)) (α T: Temperature Coefficient)
- Glass passivated chip junction
- 1500W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycles): 0.01 %
- Fast response time: typically less than 1.0ps from 0V to BV min
- Excellent clamping capability
- Low incremental surge resistance
- Typical I_R less than 1µA above 12V
- High Temperature soldering guaranteed: 260°C/40 seconds at terminals
- Plastic package has Underwriters laboratory flammability 94V-0
- Meet MSL level1, per J-STD-020, LF maximum peak of 260°C
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- 2nd level interconnect is Pb-free per IPC/JEDEC J-STD-609A.01

Applications

TVS devices are ideal for the protection of I/O Interfaces, V_{CC} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

Electrical Characteristics

Part Number (Uni)	Part Number (Bi)	Marking		Reverse Stand off Voltage V_R (Volts)	Breakdown Voltage V_{BR} (Volts) @ I_T		Test Current I_T (mA)	Maximum Clamping Voltage V_C @ I_{PP} (V)	Maximum Peak Pulse Current I_{PP} (A)	Maximum Reverse Leakage I_R @ V_R (μA)	Agency Approval 
		UNI	BI		MIN	MAX					
SMCJ5.0A-HR	SMCJ5.0CA-HR	GDE	BDE	5.0	6.40	7.00	10	9.2	163.0	800	X
SMCJ6.0A-HR	SMCJ6.0CA-HR	GDG	BDG	6.0	6.67	7.37	10	10.3	145.7	800	X
SMCJ6.5A-HR	SMCJ6.5CA-HR	GDK	BDK	6.5	7.22	7.98	10	11.2	134.0	500	X
SMCJ7.0A-HR	SMCJ7.0CA-HR	GDM	BDM	7.0	7.78	8.60	10	12.0	125.0	200	X
SMCJ7.5A-HR	SMCJ7.5CA-HR	GDP	BDP	7.5	8.33	9.21	1	12.9	116.3	100	X
SMCJ8.0A-HR	SMCJ8.0CA-HR	GDR	BDR	8.0	8.89	9.83	1	13.6	110.3	50	X
SMCJ8.5A-HR	SMCJ8.5CA-HR	GDT	BDT	8.5	9.44	10.40	1	14.4	104.2	20	X
SMCJ9.0A-HR	SMCJ9.0CA-HR	GDV	BDV	9.0	10.00	11.10	1	15.4	97.4	10	X
SMCJ10A-HR	SMCJ10CA-HR	GDZ	BDZ	10.0	11.10	12.30	1	17.0	88.3	5	X
SMCJ11A-HR	SMCJ11CA-HR	GDZ	BDZ	11.0	12.20	13.50	1	18.2	82.5	1	X
SMCJ12A-HR	SMCJ12CA-HR	GEE	BEE	12.0	13.30	14.70	1	19.9	75.4	1	X
SMCJ13A-HR	SMCJ13CA-HR	GEG	BEG	13.0	14.40	15.90	1	21.5	69.8	1	X
SMCJ14A-HR	SMCJ14CA-HR	GEK	BEK	14.0	15.60	17.20	1	23.2	64.7	1	X
SMCJ15A-HR	SMCJ15CA-HR	GEM	BEM	15.0	16.70	18.50	1	24.4	61.5	1	X
SMCJ16A-HR	SMCJ16CA-HR	GEP	BEP	16.0	17.80	19.70	1	26.0	57.7	1	X
SMCJ17A-HR	SMCJ17CA-HR	GER	BER	17.0	18.90	20.90	1	27.6	54.4	1	X
SMCJ18A-HR	SMCJ18CA-HR	GET	BET	18.0	20.00	22.10	1	29.2	51.4	1	X
SMCJ20A-HR	SMCJ20CA-HR	GEV	BEV	20.0	22.20	24.50	1	32.4	46.3	1	X
SMCJ22A-HR	SMCJ22CA-HR	GEX	BEX	22.0	24.40	26.90	1	35.5	42.3	1	X
SMCJ24A-HR	SMCJ24CA-HR	GEZ	BEZ	24.0	26.70	29.50	1	38.9	38.6	1	X
SMCJ26A-HR	SMCJ26CA-HR	GFE	BFE	26.0	28.90	31.90	1	42.1	35.7	1	X
SMCJ28A-HR	SMCJ28CA-HR	GFG	BFG	28.0	31.10	34.40	1	45.4	33.1	1	X
SMCJ30A-HR	SMCJ30CA-HR	GFK	BFK	30.0	33.30	36.80	1	48.4	31.0	1	X
SMCJ33A-HR	SMCJ33CA-HR	GFM	BFM	33.0	36.70	40.60	1	53.3	28.2	1	X
SMCJ36A-HR	SMCJ36CA-HR	GFP	BFP	36.0	40.00	44.20	1	5			

Screen Process

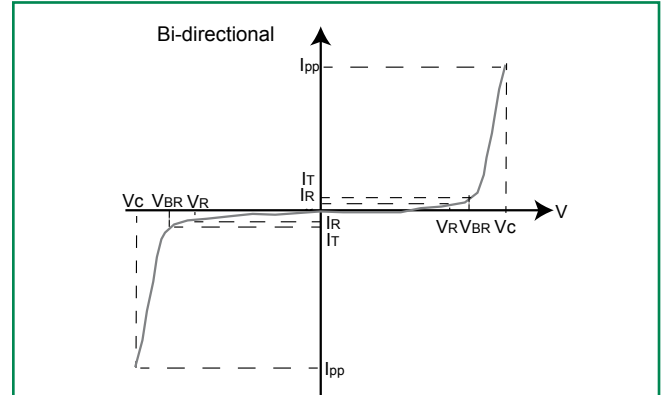
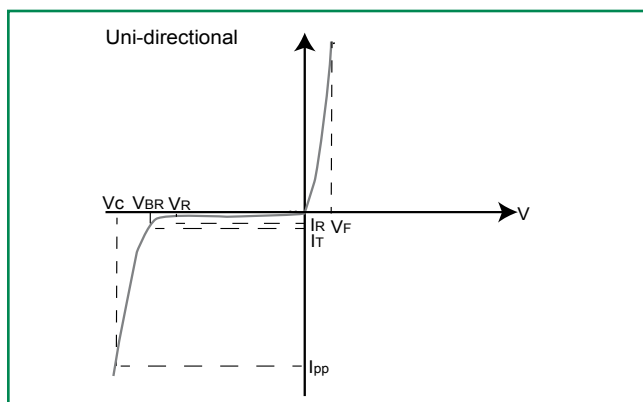
100% vision inspection	MIL-STD-750 method 2074
100%High Temperature Storage Life (168hrs,150C)	MIL-STD-750 method 1031
100% X-RAY inspection	MIL-STD-750 method 2076
100% Temperature cycle test (-55-150C, 20 cycles, dwell time 15 min)	MIL-STD-750 method 1051
100% Reflow (2X)	JEDEC J-STD-020
100% surge test (2x)	MIL-STD-750 method 4066
100% HTRB(150C, Bias=VR(80% breakdown voltage), 96hrs),for Bi-direction products, 96hrs for each direction	MIL-STD-750 method 1038
Final electrical test(100% 3 sigma limit, 100% dynamic test and PAT limit)	MIL-STD-750 method 4016.4021.4011

Note: Up-screen program can be specified by customer's request via contacting Littelfuse service

Group B Test Requirement

Screen	Method	Condition	Requirement
Surge test	10/1000 μ s Peak Pulse Waveform	Maximum Clamping Voltage (V_C) @ Peak Plus Current (I_{PP})	Sample size 45 perform 10x Accept 0 failures
Burn - In (HTRB)	MIL-STD-750, Method 1038.5	Applied Voltage 100% V_R @150°C	Sample size 45 340 hours (680 hours for bi-direction products, each direction 340 hours) Accept 0 failures
Electrical test	—	I_R @ V_R , V_{BR} @ I_T	Sample size 45 Accept 0 failures

I-V Curve Characteristics



P_{PPM} Peak Pulse Power Dissipation – Max power dissipation

V_R Stand-off Voltage – Maximum voltage that can be applied to the TVS without operation

V_{BR} Breakdown Voltage – Maximum voltage that flows through the TVS at a specified test current (I_T)

V_C Clamping Voltage – Peak voltage measured across the suppressor at a specified I_{PPM} (peak impulse current)

I_R Reverse Leakage Current – Current measured at V_R

V_F Forward Voltage Drop for Uni-directional

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

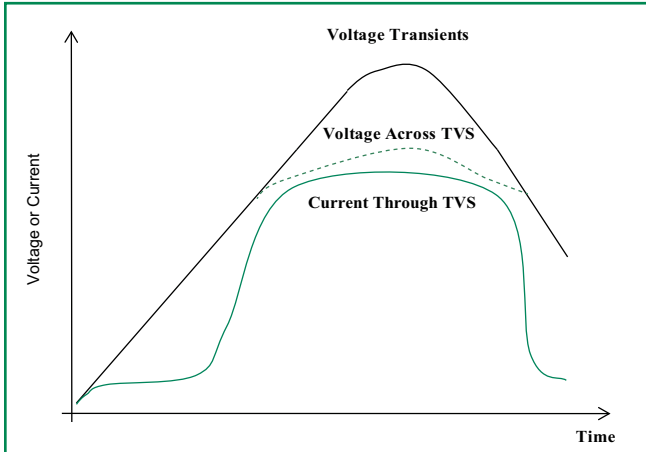


Figure 2 - Peak Pulse Power Rating

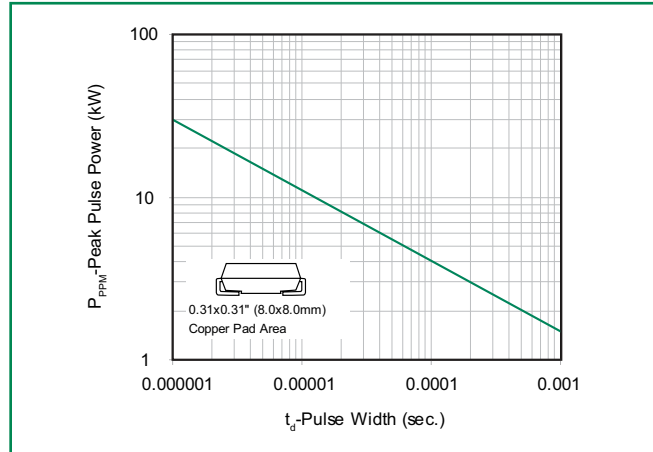


Figure 3 - Pulse Derating Curve

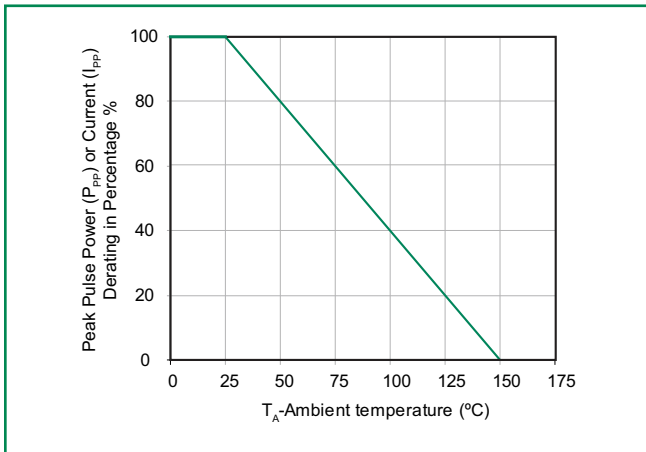


Figure 4 - Pulse Waveform

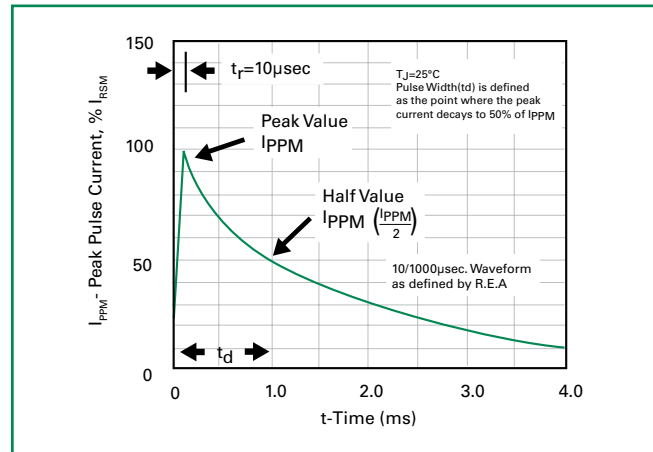


Figure 5 - Typical Junction Capacitance

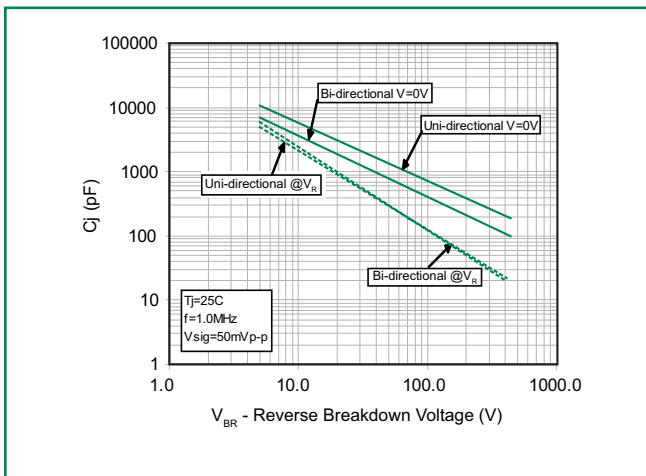


Figure 6 - Steady State Power Dissipation Derating Curve

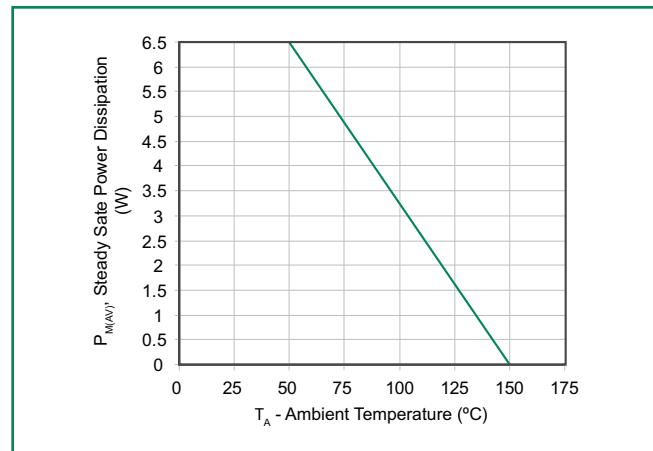
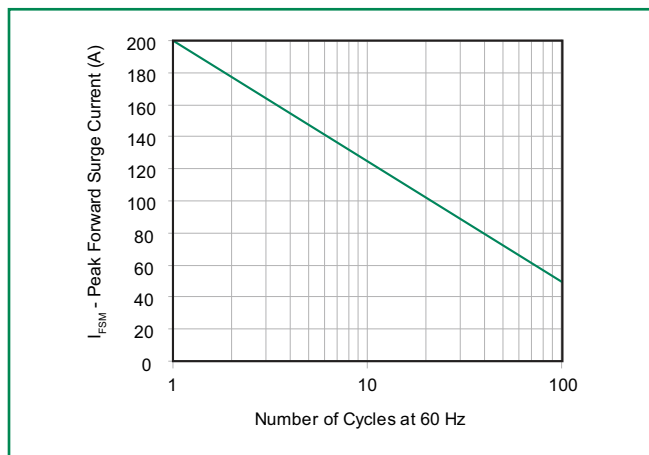
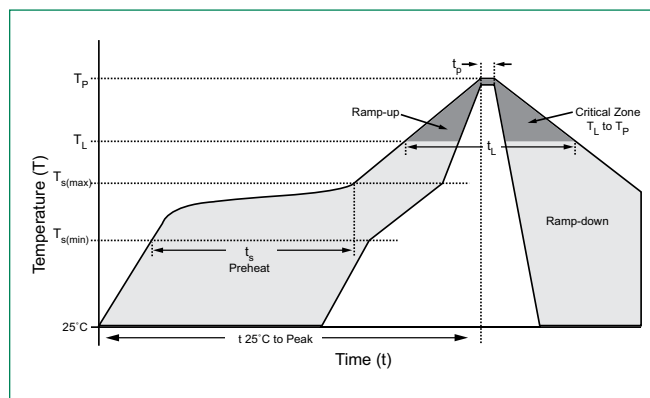


Figure 7 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Only



Soldering Parameters

Reflow Condition		Lead-free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



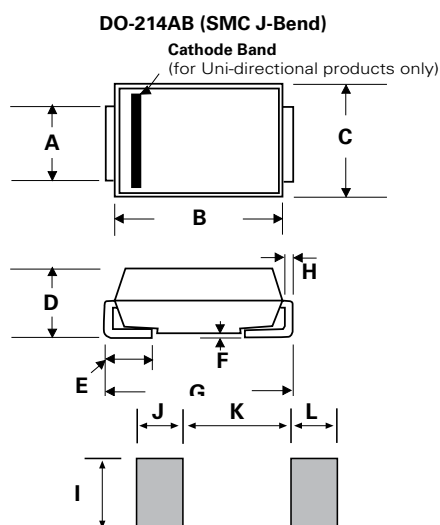
Physical Specifications

Weight	0.007 ounce, 0.21 grams
Case	JEDEC DO214AB. Molded plastic body over glass passivated junction
Polarity	Color band denotes positive end (cathode) except Bidirectional.
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102

Environmental Specifications

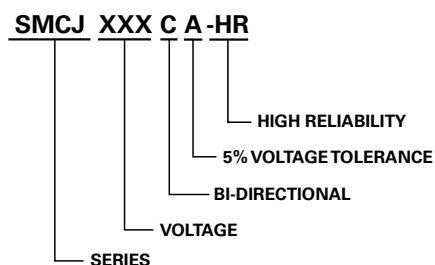
High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Thermal Shock	JESD22-A106
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-B106

Dimensions

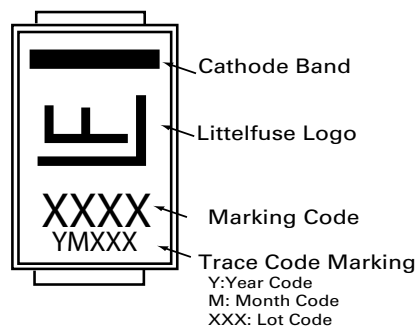


Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.114	0.126	2.900	3.200
B	0.260	0.280	6.600	7.110
C	0.220	0.245	5.590	6.220
D	0.079	0.103	2.060	2.620
E	0.030	0.060	0.760	1.520
F	0.002	0.008	0.051	0.203
G	0.305	0.320	7.750	8.130
H	0.006	0.012	0.152	0.305
I	0.129	-	3.300	-
J	0.094	-	2.400	-
K	-	0.165	-	4.200
L	0.094	-	2.400	-

Part Numbering System



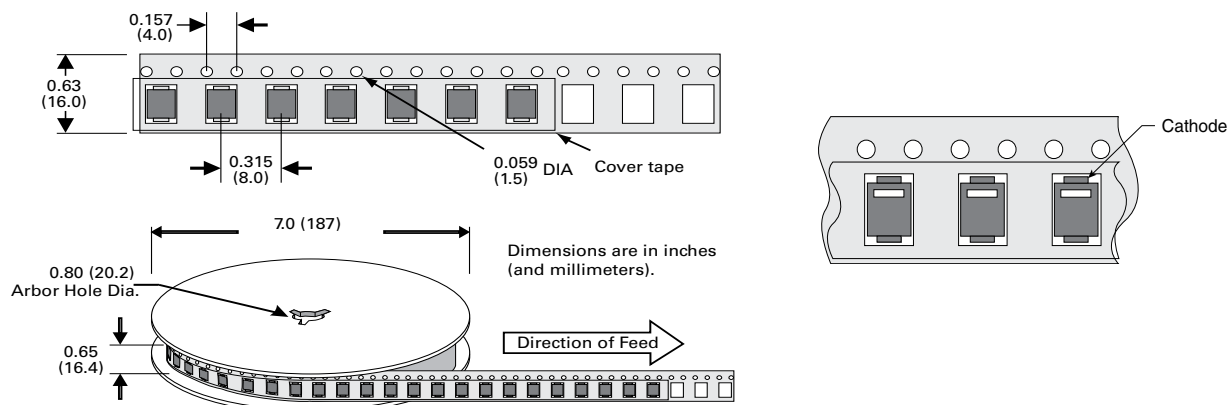
Part Marking System



Packaging

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
SMCJxxxXX-HR	DO-214AB	500	Tape & Reel – 16mm tape/7" reel	EIA STD RS-481

Tape and Reel Specification





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.